



### **60V N-CHANNEL ENHANCEMENT MODE MOSFET** PowerDI5060-8

### **Product Summary**

BV <sub>DSS</sub>	Rds(on)	I <sub>D</sub> T <sub>C</sub> = +25°C (Note 7)
60V	$8m\Omega$ @ $V_{GS} = 10V$	80A
607	12mΩ @ V <sub>GS</sub> = 4.5V	79A

# **Description and Applications**

This new generation n-channel enhancement mode MOSFET is designed to minimize RDS(ON) yet maintain superior switching performance. This device is ideal for use in notebook battery power managements and Load switches.

- Notebook battery power managements
- DC-DC converters
- Load switches

#### **Features**

- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Low RDS(ON) Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

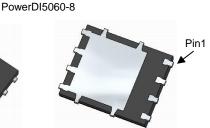
#### **Mechanical Data**

- Package: PowerDI®5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)

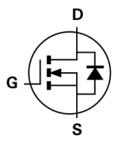




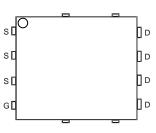
Top View



**Bottom View** 



Internal Schematic



Top View Pin Configuration

Site 2:

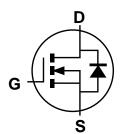
PowerDI5060-8/SWP (Type UX)



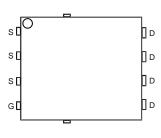
Top View



**Bottom View** 



Internal Schematic



Top View Pin Configuration

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



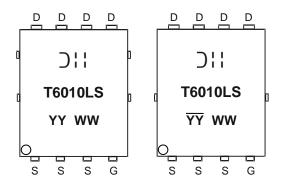
### Ordering Information (Note 4)

Part Number	Pookago	Packing		
Fait Number	Package	Qty.	Carrier	
DMT6010LPS-13	PowerDI5060-8	2,500	Tape & Reel	
DMT6010LPS-13	PowerDI5060-8/SWP (Type UX)	2,500	Tape & Reel	

Note:

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



☐ H=Manufacturer's Marking T6010LS = Product Type Marking Code YYWW = Date Code Marking YY or YY = Last Two Digits of Year (ex: 23 = 2023) WW = Week Code (01 to 53)

# **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		VDSS	60	V
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current (Note 5)	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	lD	13.5 11	А
Continuous Drain Current (Note 6)	T <sub>C</sub> = +25°C (Note 7) T <sub>C</sub> = +70°C	lo	80 77	А
Maximum Continuous Body Diode Forward Current (Note 6)		Is	80	Α
Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%)		IDM	125	А
Avalanche Current, L=0.1mH		las	20	А
Avalanche Energy, L=0.1mH		E <sub>AS</sub>	20	mJ

### **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	2.2	W
Thermal Resistance, Junction to Ambient (Note 5)		Reja	57	°C/W
Total Power Dissipation (Note 6)	$T_{C} = +25^{\circ}C$	P <sub>D</sub>	113	W
Thermal Resistance, Junction to Case (Note 6)	<u>.</u>	Rejc	1.1	°C/W
Operating and Storage Temperature Range		T <sub>J.</sub> T <sub>STG</sub>	-55 to +150	°C

5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.6. Thermal resistance from junction to soldering point (on the exposed drain pad).7. Package limited. Notes:



# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	_	_	V	$V_{GS} = 0V$ , $I_D = 1mA$
Zero Gate Voltage Drain Current	IDSS	_	_	1	μΑ	V <sub>DS</sub> = 48V, V <sub>GS</sub> = 0V
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	Vgs(TH)	1	_	3	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$
Static Drain-Source On-Resistance	Daggan	1	6	8	mΩ	$V_{GS} = 10V, I_{D} = 20A$
Static Dialif-Source Off-Resistance	RDS(ON)	_	8	12	11177	$V_{GS} = 4.5V, I_{D} = 20A$
Diode Forward Voltage	$V_{SD}$	_	0.9	1.2	V	$V_{GS} = 0V, I_{S} = 20A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss		2090	_		V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V, f = 1MHz
Output Capacitance	Coss		746	_	pF	
Reverse Transfer Capacitance	Crss	_	38.5	_		
Gate Resistance	Rg	_	0.59	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	19.3	_		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	41.3	_	nC	V <sub>DS</sub> = 30V, I <sub>D</sub> = 20A
Gate-Source Charge	Qgs		6.0	_	nc nc	
Gate-Drain Charge	Qgd	_	8.8	_		
Turn-On Delay Time	t <sub>D(ON)</sub>	_	5.7	_		
Turn-On Rise Time	t <sub>R</sub>	_	4.3	_		$V_{DD} = 30V, V_{GS} = 10V,$ $I_{D} = 20A, R_{G} = 3\Omega$
Turn-Off Delay Time	tD(OFF)	_	23.4	_	ns	
Turn-Off Fall Time	tF	_	9.7	_		
Body Diode Reverse Recovery Time	trr	_	35.4	_	ns	1 000 11/14 1000/
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	_	38.2		nC	I <sub>F</sub> = 20A, di/dt = 100A/μs

Notes:

Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.



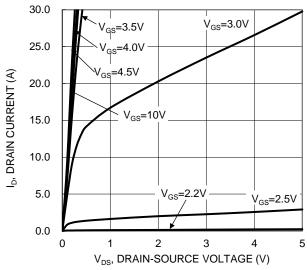


Figure 1. Typical Output Characteristic

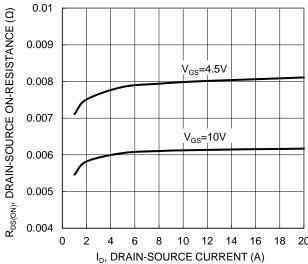


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

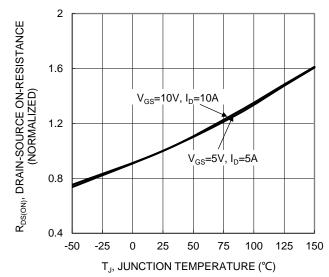


Figure 5. On-Resistance Variation with Temperature

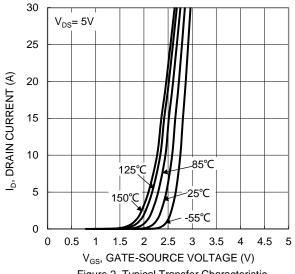


Figure 2. Typical Transfer Characteristic

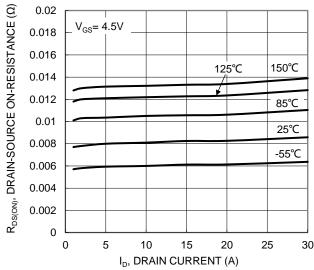


Figure 4. Typical On-Resistance vs. Drain Current and Temperature

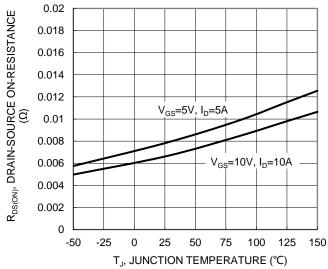
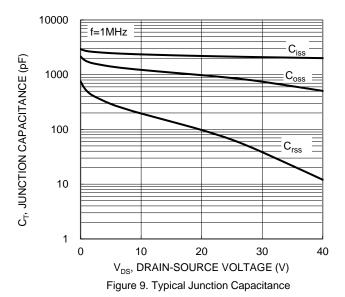


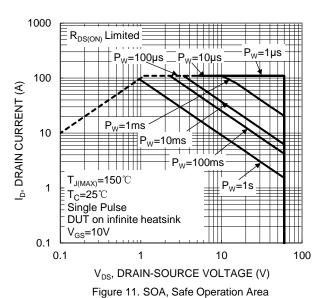
Figure 6. On-Resistance Variation with Temperature



#### 2 $V_{GS(TH)}$ , GATE THRESHOLD VOLTAGE (V) 1.8 1.6 $I_D=1mA$ 1.4 1.2 1 I<sub>D</sub>=250μA 8.0 0.6 0.4 0.2 -50 -25 25 50 75 100 125 150 T<sub>J</sub>, JUNCTION TEMPERATURE (°C)

Figure 7. Gate Threshold Variation vs. Junction Temperature





### DMT6010LPS

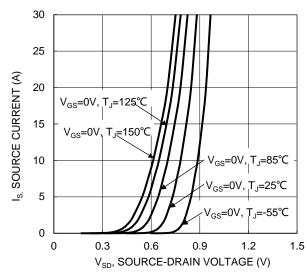


Figure 8. Diode Forward Voltage vs. Current

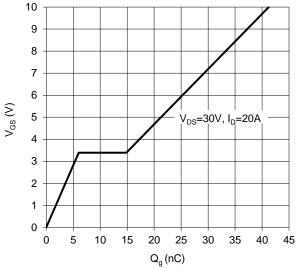


Figure 10. Gate Charge



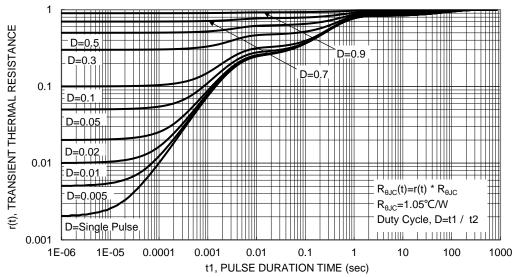


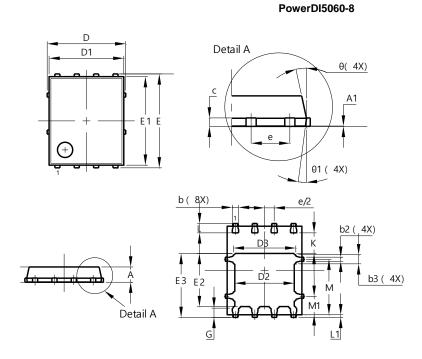
Figure 12. Transient Thermal Resistance



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

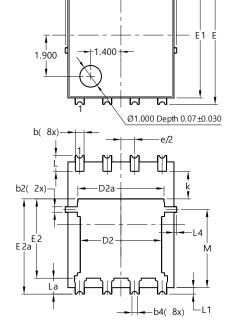
#### Site 1:



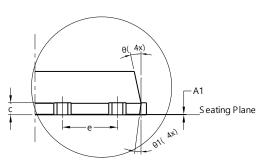
PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
<b>A</b> 1	0.00	0.05	_		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	Į.	5.15 BSC	,		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
Е	•	6.15 BSC	,		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	-	-		
٦	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All Dimensions in mm					
7 2CCOIIO III IIIII					

Site 2:

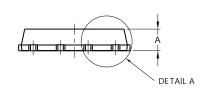
### PowerDI5060-8/SWP (Type UX)



-D1



DETAIL A



Dim   Min   Max   Typ     A   0.90   1.10   1.00     A1   0   0.05       b   0.30   0.50   0.41     b2   0.20   0.35   0.25     b4   0.25REF     c   0.230   0.330   0.277     D   5.15 BSC     D1   4.70   5.10   4.90     D2   3.56   3.96   3.76     D2a   3.78   4.18   3.98     E   6.40 BSC     E1   5.60   6.00   5.80     E2   3.46   3.86   3.66     E2a   4.195   4.595   4.395     e   1.27BSC     k   1.05         L   0.635   0.835   0.735     La   0.635   0.835   0.735     La   0.025   0.225   0.125     M   3.205   4.005   3.605     θ   10°   12°   11°     θ1   6°   8°   7°     All Dimensions in mm	PowerDI5060-8/SWP (Type UX)				
A1         0         0.05            b         0.30         0.50         0.41           b2         0.20         0.35         0.25           b4         0.25REF         0.230         0.330         0.277           D         5.15 BSC           D1         4.70         5.10         4.90           D2         3.56         3.96         3.76           D2a         3.78         4.18         3.98           E         6.40 BSC           E1         5.60         6.00         5.80           E2         3.46         3.86         3.66           E2a         4.195         4.595         4.395           e         1.27BSC           k         1.063         0.835         0.735           La         0.635         0.835         0.735           La         0.635         0.835         0.735           L1         0.200         0.400         0.300           L1a         0.050REF           L4         0.025         0.225         0.125           M         3.205         4.005         3.605           θ         10°         1	Dim			Тур	
b         0.30         0.50         0.41           b2         0.20         0.35         0.25           b4         0.25REF         c         0.230         0.330         0.277           D         5.15 BSC           D1         4.70         5.10         4.90           D2         3.56         3.96         3.76           D2a         3.78         4.18         3.98           E         6.40 BSC           E1         5.60         6.00         5.80           E2         3.46         3.86         3.66           E2a         4.195         4.595         4.395           e         1.27BSC         k         1.05            L         0.635         0.835         0.735           La         0.635         0.835         0.735           L1         0.200         0.400         0.300           L1a         0.025         0.225         0.125           M         3.205         4.005         3.605           θ         10°         12°         11°           θ1         6°         8°         7°	Α	0.90	1.10	1.00	
b2         0.20         0.35         0.25           b4         0.25REF           c         0.230         0.330         0.277           D         5.15 BSC           D1         4.70         5.10         4.90           D2         3.56         3.96         3.76           D2a         3.78         4.18         3.98           E         6.40 BSC           E1         5.60         6.00         5.80           E2         3.46         3.86         3.66           E2a         4.195         4.595         4.395           e         1.27BSC           k         1.05             L         0.635         0.835         0.735           La         0.635         0.835         0.735           L1         0.200         0.400         0.300           L1a         0.025         0.225         0.125           M         3.205         4.005         3.605           θ         10°         12°         11°           θ1         6°         8°         7°	A1	0	0.05		
b4         0.25REF           c         0.230         0.330         0.277           D         5.15 BSC           D1         4.70         5.10         4.90           D2         3.56         3.96         3.76           D2a         3.78         4.18         3.98           E         6.40 BSC           E1         5.60         6.00         5.80           E2         3.46         3.86         3.66           E2a         4.195         4.595         4.395           e         1.27BSC         k         1.05            L         0.635         0.835         0.735           La         0.635         0.835         0.735           L1         0.200         0.400         0.300           L1a         0.050REF           L4         0.025         0.225         0.125           M         3.205         4.005         3.605           θ         10°         12°         11°           θ1         6°         8°         7°	b	0.30	0.50	0.41	
c         0.230         0.330         0.277           D         5.15 BSC           D1         4.70         5.10         4.90           D2         3.56         3.96         3.76           D2a         3.78         4.18         3.98           E         6.40 BSC           E1         5.60         6.00         5.80           E2         3.46         3.86         3.66           E2a         4.195         4.595         4.395           e         1.27BSC         k         1.05            L         0.635         0.835         0.735           La         0.635         0.835         0.735           La         0.635         0.835         0.735           L1         0.200         0.400         0.300           L1a         0.050REF           L4         0.025         0.225         0.125           M         3.205         4.005         3.605           θ         10°         12°         11°           θ1         6°         8°         7°	b2	0.20	0.35	0.25	
D         5.15 BSC           D1         4.70         5.10         4.90           D2         3.56         3.96         3.76           D2a         3.78         4.18         3.98           E         6.40 BSC           E1         5.60         6.00         5.80           E2         3.46         3.86         3.66           E2a         4.195         4.595         4.395           e         1.27BSC         k         1.05            L         0.635         0.835         0.735           La         0.635         0.835         0.735           La         0.635         0.835         0.735           L1         0.200         0.400         0.300           L1a         0.050REF           L4         0.025         0.225         0.125           M         3.205         4.005         3.605           θ         10°         12°         11°           θ1         6°         8°         7°	b4	(	).25REF	•	
D1         4.70         5.10         4.90           D2         3.56         3.96         3.76           D2a         3.78         4.18         3.98           E         6.40 BSC           E1         5.60         6.00         5.80           E2         3.46         3.86         3.66           E2a         4.195         4.595         4.395           e         1.27BSC         L           L         0.635         0.835         0.735           La         0.635         0.835         0.735           L1         0.200         0.400         0.300           L1a         0.050REF           L4         0.025         0.225         0.125           M         3.205         4.005         3.605           θ         10°         12°         11°           θ1         6°         8°         7°		0.230	0.330	0.277	
D2         3.56         3.96         3.76           D2a         3.78         4.18         3.98           E         6.40 BSC         6.00         5.80           E1         5.60         6.00         5.80           E2         3.46         3.86         3.66           E2a         4.195         4.595         4.395           e         1.27BSC             L         0.635         0.835         0.735           La         0.635         0.835         0.735           L1         0.200         0.400         0.300           L1a         0.050REF           L4         0.025         0.225         0.125           M         3.205         4.005         3.605           θ         10°         12°         11°           θ1         6°         8°         7°		5	.15 BS0	)	
D2a         3.78         4.18         3.98           E         6.40 BSC           E1         5.60         6.00         5.80           E2         3.46         3.86         3.66           E2a         4.195         4.595         4.395           e         1.27BSC            k         1.05             L         0.635         0.835         0.735           La         0.635         0.835         0.735           L1         0.200         0.400         0.300           L1         0.050RE            L4         0.025         0.225         0.125           M         3.205         4.005         3.605           θ         10°         12°         11°           θ1         6°         8°         7°	D1	4.70	5.10	4.90	
E 6.40 BSC  E1 5.60 6.00 5.80  E2 3.46 3.86 3.66  E2a 4.195 4.595 4.395  e 1.27BSC  k 1.05  L 0.635 0.835 0.735  La 0.635 0.835 0.735  L1 0.200 0.400 0.300  L1a 0.050REF  L4 0.025 0.225 0.125  M 3.205 4.005 3.605  θ 10° 12° 11°  θ1 6° 8° 7°	D2	3.56	3.96	3.76	
E1 5.60 6.00 5.80  E2 3.46 3.86 3.66  E2a 4.195 4.595 4.395  e 1.27BSC  k 1.05  L 0.635 0.835 0.735  La 0.635 0.835 0.735  L1 0.200 0.400 0.300  L1a 0.050REF  L4 0.025 0.225 0.125  M 3.205 4.005 3.605  θ 10° 12° 11°  θ1 6° 8° 7°	D2a	3.78	4.18	3.98	
E2       3.46       3.86       3.66         E2a       4.195       4.595       4.395         e       1.27BSC       k       1.05           L       0.635       0.835       0.735       0.835       0.735         La       0.635       0.835       0.735       0.135         L1       0.200       0.400       0.300         L1a       0.050REF         L4       0.025       0.225       0.125         M       3.205       4.005       3.605         θ       10°       12°       11°         θ1       6°       8°       7°	_	6	.40 BS0	)	
E2a       4.195       4.595       4.395         e       1.27BSC         k       1.05           L       0.635       0.835       0.735         La       0.635       0.835       0.735         L1       0.200       0.400       0.300         L1a       0.050REF         L4       0.025       0.225       0.125         M       3.205       4.005       3.605         θ       10°       12°       11°         θ1       6°       8°       7°	E1		6.00	5.80	
e         1.27BSC           k         1.05             L         0.635         0.835         0.735           La         0.635         0.835         0.735           L1         0.200         0.400         0.300           L1a         0.050REF           L4         0.025         0.225         0.125           M         3.205         4.005         3.605           θ         10°         12°         11°           θ1         6°         8°         7°	E2	3.46	3.86	3.66	
k         1.05             L         0.635         0.835         0.735           La         0.635         0.835         0.735           L1         0.200         0.400         0.300           L1a         0.050REF           L4         0.025         0.225         0.125           M         3.205         4.005         3.605           θ         10°         12°         11°           θ1         6°         8°         7°	E2a	4.195	4.595	4.395	
L 0.635 0.835 0.735 La 0.635 0.835 0.735 L1 0.200 0.400 0.300 L1a 0.050REF L4 0.025 0.225 0.125 M 3.205 4.005 3.605 θ 10° 12° 11° θ1 6° 8° 7°	_	1	.27BSC	)	
$ \begin{array}{c cccc} \textbf{La} & 0.635 & 0.835 & 0.735 \\ \textbf{L1} & 0.200 & 0.400 & 0.300 \\ \textbf{L1a} & & 0.050 \text{REF} \\ \textbf{L4} & 0.025 & 0.225 & 0.125 \\ \textbf{M} & 3.205 & 4.005 & 3.605 \\ \textbf{\theta} & 10^{\circ} & 12^{\circ} & 11^{\circ} \\ \textbf{\theta1} & 6^{\circ} & 8^{\circ} & 7^{\circ} \\ \end{array} $	k	1.05			
L1         0.200         0.400         0.300           L1a         0.050REF           L4         0.025         0.225         0.125           M         3.205         4.005         3.605           θ         10°         12°         11°           θ1         6°         8°         7°	_	0.635	0.835	0.735	
L1a         0.050REF           L4         0.025         0.225         0.125           M         3.205         4.005         3.605           θ         10°         12°         11°           θ1         6°         8°         7°		0.635	0.835	0.735	
L4         0.025         0.225         0.125           M         3.205         4.005         3.605           θ         10°         12°         11°           θ1         6°         8°         7°	L1				
M         3.205         4.005         3.605           0         10°         12°         11°           01         6°         8°         7°		0.050REF			
θ         10°         12°         11°           θ1         6°         8°         7°	L4	0.025	0.225	0.125	
<b>θ1</b> 6° 8° 7°					
**	_	_			
All Dimensions in mm			_	•	
אוווו פווטופווסוטווט ווו ווווווו					

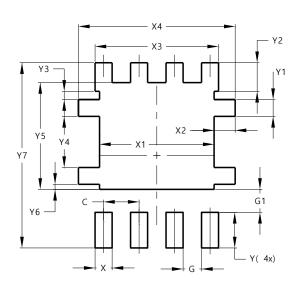


# **Suggested Pad Layout**

 $\label{prop:lease} Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$ 

Site 1:

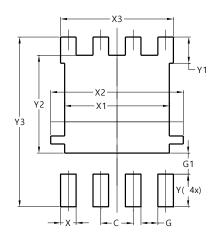
### PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
Х3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

### PowerDI5060-8/SWP (Type UX)



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
X	0.610
X1	4.100
X2	5.190
Х3	4.420
Υ	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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